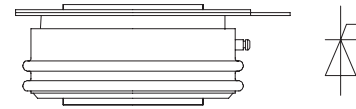


FEATURES

- | | | |
|-------------------------------------|-------------------|----------------|
| 1). Interdigitated amplifying gates | $I_{T(AV)}$ | 426A |
| 2). Fast turn-on and high di/dt | V_{DRM}/V_{RRM} | 800~1600V |
| 3). Low switching losses | t_q | 24~50 μ s |
| | I_{TSM} | 4.3KA |
| | I^2t | 92 $10^3 A^2S$ |

TYPICAL APPLICATIONS

- 1). Inductive heating
- 2). Electronic welders
- 3). Self-commutated inverters



THE MAIN PARAMETERS

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_J(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled, $T_{hs}=55^{\circ}C$	125			426	A
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V_{DRM} & V_{RRM} , $t_p=10ms$ V_{DSM} & $V_{RSM} = V_{DRM}$ & $V_{RRM} + 100V$	125	800		1600	V
I_{DRM} I_{RRM}	Repetitive peak off-state current Repetitive peak reverse current	$V_D = V_{DRM}$ $V_R = V_{RRM}$	125			30	mA
I_{TSM} I^2t	Surge on-state current I^2T for fusing coordination	10ms half sine wave $V_R=0.6V_{RRM}$	125			4.3 92	KA $A^2s \cdot 10^3$
V_{TO}	Threshold voltage		125			1.60	V
r_T	On-state slop resistance		125			1.32	$m\Omega$
V_{TM}	Peak on-state voltage	$I_{TM}=1000A$, $F=7.0KN$	125			2.92	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			500	$V/\mu s$
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ to 800A, Gate pulse $t_r \leq 0.5 \mu s$ $I_{GM}=1.5A$	125			1000	$A/\mu s$
I_m	Reverse recovery current	$I_{TM}=500A$, $t_p=1000 \mu s$, $di/dt=-20A/\mu s$, $VR=50V$	125		49		A
t_{rr}	Reverse recovery time				3.4		μs
Q_{rr}	Recovery charge				83	100	μC
t_q	Circuit commutated turn-off time	$I_{TM}=500A$, $t_p=1000 \mu s$, $V_R=50V$ $dv/dt=30V/\mu s$, $di/dt=-20A/\mu s$	125	24		50	μs
I_{GT}	Gate trigger current			40		250	mA
V_{GT}	Gate trigger voltage	$V_A=12V$, $I_A=1A$	25	0.9		42.5	V
I_H	Holding current			20		400	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.3			V
$R_{th(j-h)}$	Thermal resistance Junction to heatsink	At 180° sine, double side cooled Clamping force 7.0KN				0.055	$^{\circ}C/W$
F_m	Mounting force			5.3		10	KN
T_{stg}	Stored temperature			-40		140	$^{\circ}C$
W_t	Weight				80		g
Size	Package box size			95 × 95 × 50			mm

PERFORMANCE CURVES FIGURE

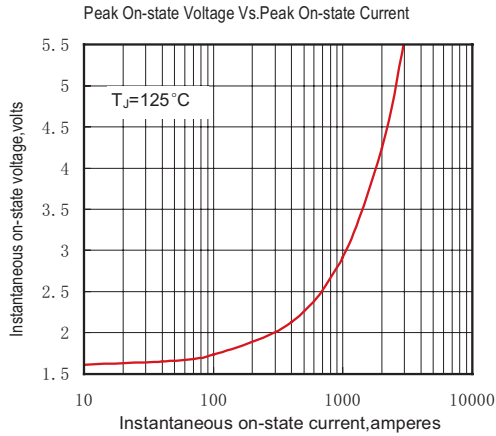


Fig.1

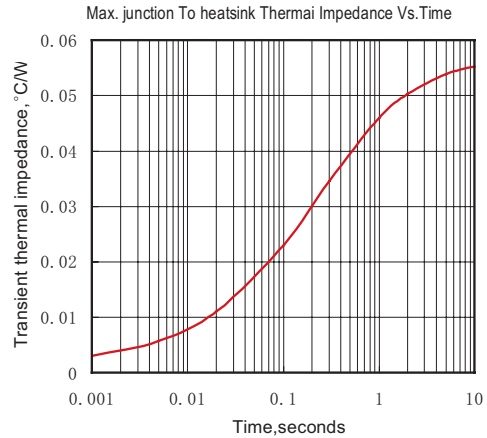


Fig.2

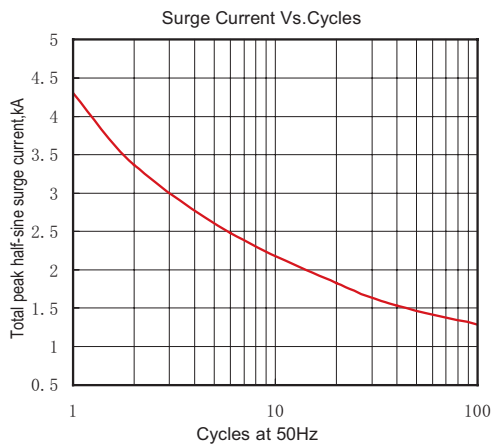


Fig.3

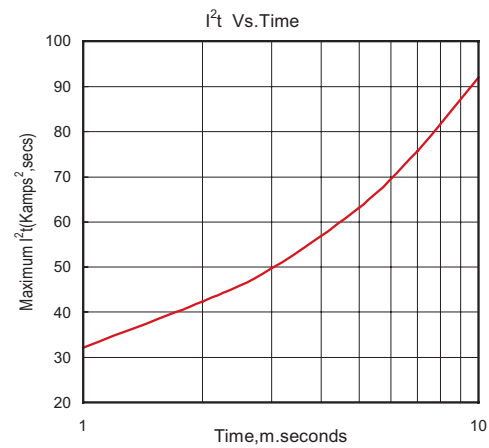


Fig.4

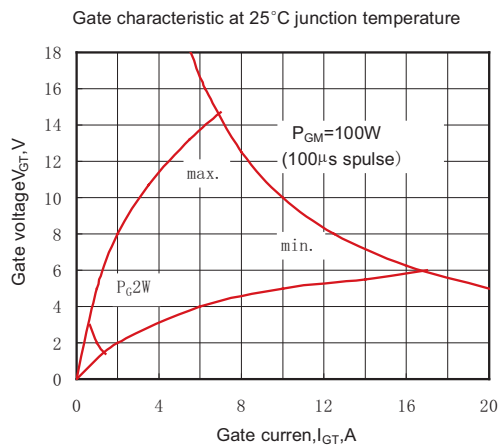


Fig.5

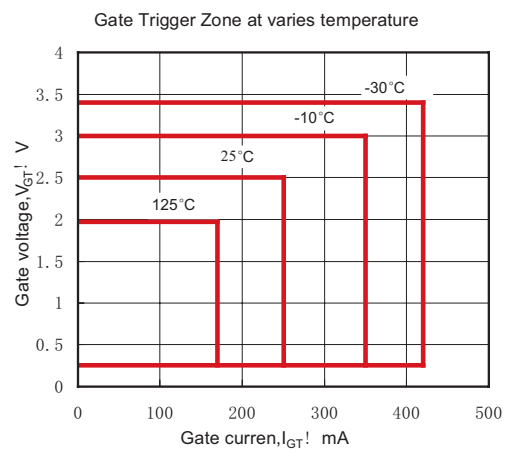
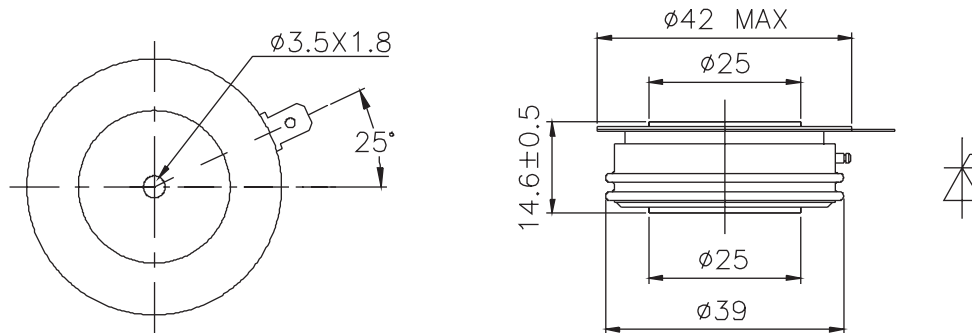


Fig.6

OUTLINE



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